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Texas Instruments BQ24105IRHLRQ1

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bq24105-Q1

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# SYNCHRONOUS SWITCHMODE, LI-ION AND LI-POLYMER CHARGE-MANAGEMENT IC WITH INTEGRATED POWER FETs ( bgSWITCHER™)

Check for Samples: bg24105-Q1

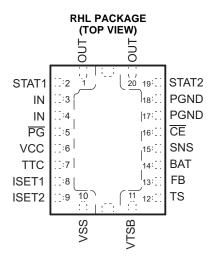
## **FEATURES**

- **Qualified for Automotive Applications**
- Ideal For Highly Efficient Charger Designs For Single-, Two-, or Three-Cell Li-Ion and Li-**Polymer Battery Packs**
- Also for LiFePO₄ Battery (see Using bq24105 to Charge LiFePO4 Battery)
- Integrated Synchronous Fixed-Frequency **PWM Controller Operating at 1.1 MHz** With 0% to 100% Duty Cycle
- Integrated Power FETs For Up To 2-A Charge Rate
- **High-Accuracy Voltage and Current Regulation**
- Stand-Alone (Built-In Charge Management and **Control) Version**
- Status Outputs For LED or Host Processor Interface Indicates Charge-In-Progress, Charge Completion, Fault, and AC-Adapter Present Conditions
- 20-V Maximum Voltage Rating on IN and OUT Pins
- **High-Side Battery Current Sensing**
- **Battery Temperature Monitoring**
- Automatic Sleep Mode for Low Power Consumption
- **Reverse Leakage Protection Prevents Battery** Drainage
- **Thermal Shutdown and Protection**
- **Built-In Battery Detection**
- Available in 20-Pin, 3.5 mm × 4.5 mm, QFN Package

## DESCRIPTION

The bqSWITCHER<sup>™</sup> series are highly integrated Liion and Li-polymer switch-mode charge management devices targeted at a wide range of portable applications. The bqSWITCHER™ series offers integrated synchronous PWM controller and power FETs, high-accuracy current and voltage regulation, charge preconditioning, charge status, and charge termination, in a small, thermally enhanced QFN package.

The bqSWITCHER charges the battery in three phases: conditioning, constant current, and constant voltage. Charge is terminated based on userselectable minimum current level. A programmable charge timer provides a safety backup for charge termination. The bqSWITCHER automatically restarts the charge cycle if the battery voltage falls below an internal threshold. The bqSWITCHER automatically enters sleep mode when V<sub>CC</sub> supply is removed.





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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### **ORDERING INFORMATION**<sup>(1)</sup>

T <sub>A</sub>	PACK	AGE <sup>(2)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	QFN – RHL	Reel of 3000	BQ24105IRHLRQ1	BQ24105

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

	Supply voltage range (with respect to V <sub>SS</sub> )	IN, VCC	20 V
		STAT1, STAT2, PG, CE, SNS, BAT	–0.3 V to 20 V
		OUT	–0.7 V to 20 V
	Input voltage range (with respect to $V_{SS}$ and $PGND)$	TS, TTC	7 V
		VTSB	3.6 V
		ISET1, ISET2	3.3 V
	Voltage difference between SNS and BAT inputs (V $_{\rm S}$	<sub>NS</sub> – V <sub>BAT</sub> )	±1 V
	Output sink	STAT1, STAT2, PG	10 mA
	Output current (average)	OUT	2.2 A
Γ <sub>Α</sub>	Operating free-air temperature range		-40°C to 85°C
Γ <sub>J</sub>	Junction temperature range		-40°C to 125°C
stg	Storage temperature		–65°C to 150°C
	Lead temperature 1,6 mm (1/16 inch) from case for 1	0 seconds	300°C

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### PACKAGE DISSIPATION RATINGS

PACKAGE	θ <sub>JA</sub>	θ <sub>JC</sub>	T <sub>A</sub> < 40°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 40°C
RHL <sup>(1)</sup>	46.87°C/W	2.5°C/W	1.81 W	0.021 W/°C

(1) This data is based on using the JEDEC High-K board, and the exposed die pad is connected to a copper pad on the board. This is connected to the ground plane by a 2x3 via matrix.

#### **RECOMMENDED OPERATING CONDITIONS**

	MIN	MAX	UNIT
Supply voltage, V <sub>CC</sub> and IN (Tie together)	4.35 <sup>(1)</sup>	16 <sup>(2)</sup>	V
Operating junction temperature range, T <sub>J</sub>	-40	125	°C

(1) The IC continues to operate below V<sub>min</sub>, to 3.5 V, but the specifications are not tested and not specified.

(2) The inherent switching noise voltage spikes should not exceed the absolute maximum rating on either the IN or OUT pins. A *tight* layout minimizes switching noise.

## ELECTRICAL CHARACTERISTICS

 $T_J = 0^{\circ}C$  to 125°C and recommended supply voltage range (unless otherwise stated)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Currents					



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### **ELECTRICAL CHARACTERISTICS (continued)**

 $T_J = 0^{\circ}C$  to 125°C and recommended supply voltage range (unless otherwise stated)

Image: Constraint of the second constraint		PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$ \begin{split} & \text{Vacc supply current} & \underbrace{V_{\text{CC}} = V_{\text{CC}\text{SP}} \text{PVM NOT sutching}}_{V_{\text{CC}} = V_{\text{CC}\text{SP}}, \text{CE} = \text{HIGH}} & 316 & \mu \mu \\ & V_{\text{CC}} = V_{\text{CC}\text{SP}}, \text{CE} = \text{HIGH}} & 316 & \mu \mu \\ & V_{\text{CC}} = V_{\text{CC}\text{SP}}, \text{CE} = \text{HIGH}} & 316 & \mu \mu \\ & V_{\text{CC}} = V_{\text{CC}\text{SP}}, \text{CE} = \text{HIGH}} & 316 & \mu \mu \\ & V_{\text{CC}} = V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}} = 4.2 \text{ V}, \\ & V_{\text{CC}} = V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}} = 4.2 \text{ V}, \\ & V_{\text{CC}} = V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}} = 4.2 \text{ V}, \\ & V_{\text{CC}} = V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}} = 4.2 \text{ V}, \\ & V_{\text{CC}} = V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}} = 0.5 \text{ F}, \\ & V_{\text{CC}} = V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}} = 0.5 \text{ F}, \\ & V_{\text{CC}} = V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}} = 0.5 \text{ F}, \\ & V_{\text{CC}} = V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}} = 0.5 \text{ F}, \\ & V_{\text{CC}} = V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, V_{\text{CC}\text{SP}}, V_{\text{CC}\text{SP}}, \text{SE}, V_{\text{CC}\text{SP}}, V_{\text{CC}\text{SP}}$			V <sub>CC</sub> > V <sub>CC(min)</sub> , PWM switching		10		A
ViewV	(VCC)	V <sub>CC</sub> supply current	V <sub>CC</sub> > V <sub>CC(min)</sub> , PWM NOT switching			5	mA
$ I_{SUP} \begin{tabular}{ c c c c } \hline Barting discharge sleep current, ISNS, \\ I_{SUP} \begin{tabular}{ c c c c } \hline Barting discharge sleep current, ISNS, \\ \hline I_{SUP} \begin{tabular}{ c c c c } \hline Barting discharge sleep current, ISNS, \\ \hline I_{SUP} \begin{tabular}{ c c c c } \hline Barting discharge sleep current, ISNS, \\ \hline I_{SUP} \begin{tabular}{ c c c c } \hline Barting discharge sleep current, ISNS, \\ \hline I_{SUP} \begin{tabular}{ c c c } \hline Barting discharge sleep current, ISNS, \\ \hline I_{SUP} \begin{tabular}{ c c } \hline Barting discharge sleep current, ISNS, \\ \hline I_{SUP} \begin{tabular}{ c c } \hline I_{SUP$			$V_{CC} > V_{CC(min)}, \overline{CE} = HIGH$			315	μA
BAT, OUT, FB pins)         Voc < V(g_2) of Voc > V(g_2) but not in charge			$0^{\circ}C \le T_{J} \le 65^{\circ}C, V_{I(BAT)} = 4.2 V,$			3.5	
Voc. < V <sub>(BLP</sub> ) or V <sub>OC</sub> > V <sub>(BLP</sub> ) put not in charge         //           Voltage Regulation         Feedback regulation REF for bg24105 $I_{BAT} = 25 \text{ nA typical into pin}$ 2.1         V           Voltage regulation accuracy         T <sub>a</sub> = 25 °C         -0.5%         0.5%	I <sub>(SLP)</sub>					5.5	μA
Feedback regulation REF for bq24105 $I_{axt} = 25 nA typical into pin         2.1         V           Voltage regulation accuracy         Ta = 25°C         -0.5%         0.5%           Current Regulation - Fast Charge         -1%         1%           Conserved         Output current range of converter         V_cow 5 Villact, 5 Volce.VVCCC - Villact, 5 Volce.VVCCC - Villact, 5 Volce.         150         2000         m/           Village         Output current range of converter         Village scale of the second of$						7.7	
Visit (W)(FB)         Itext # 25 fix typical into pin         2.1         V           Votage regulation accuracy $T_A = 25^{\circ}$ C         -0.5%         0.5%           Current Regulation - Fast Charge         -1%         150         2000         mit           Votage regulation accuracy         V.cov 5 Vigat) < Voteo. Voteo - Vigat) > Voteo Mark         150         2000         mit           Votage regulated across R <sub>(505</sub> ) Accuracy         Viceo - Vigath > Voteo. Viceo - Vigath > 160         150         2000         mit           Vireco - Vigath > Votage regulated across R <sub>(505</sub> ) Accuracy         Viceo - Vigath > Viceo accuracy         -10%         10%         -10%         10%         Viceo - Vigath > Viceo accuracy         Viceo - Vigath > Viceo accuracy         -10%         10%         Viceo - Vigath > Viceo accuracy         Viceo - Vigath > Viceo accuracy         -10%         10%         Viceo - Vigath > Viceo accuracy         Viceo - Vigath > Viceo accuracy         -10%         10%         Viceo - Vigath > Viceo accuracy         10%         <	Voltage Re	egulation					
Voltage regulation accuracy         -1%         1%           Current Regulation - Fast Charge         V.cow S Mustry < Yoste: Vrccc - Viext > Vie	V <sub>IBAT</sub>		I <sub>IBAT</sub> = 25 nA typical into pin		2.1		V
Current Regulation - Fast ChargeV_CORP V [IBAT] < VOREG- VCCG - VIBAT] > VOREG- VCCG - VIBAT] > VOREG- VCCG - VIBAT] > VOREGA1502000m/000H8002Output current range of converterV_CORP - VIBAT) > VOREGA VCCG - VIBAT) > VOREGA1502000m/VIBEGINO W \$ VIBEGS 200 mV. VIBEGS 200 mV.VIBEGS EXENT VIBEGS 200 mV10%100%\$VIBEGRSET1 \$ 10 K0, Select RSET1 to program VARGA VIECES-MARGE + Rave (-10% to 10% excludes errors due to RSET1 		Voltage regulation accuracy	$T_A = 25^{\circ}C$	-0.5%		0.5%	
Output current range of converter $V_{LOWY} \leq V_{REAT} < V_{ORCIG.}$ $V_{LOCO} - V_{REAT} > V_{ORCIG.}$ 150         2000         m/ $V_{REG}$ Voltage regulated across $R_{(SNS)}$ Accuracy $V_{REG} = \frac{1}{RSET1} \times 1000.$ $V_{IREG} = \frac{1}{RSET1} \times 1000.$ $-10\%$ $10\%$ $V_{REG}$ Voltage regulated across $R_{(SNS)}$ Accuracy $V_{IREG} = \frac{1}{RSET1} \times 1000.$ $-10\%$ $10\%$ $V_{IREG}$ Output current set voltage $V_{LOWY} \leq V_{REG} + R_{SNS}$ $-10\%$ $10\%$ $V_{IRET1}$ Output current set voltage $V_{LOWY} \leq V_{IRET} > V_{ORCIG} > V_{VICCI} > V_{$		voltage regulation accuracy		-1%		1%	
ContractsOutput current range of convention $V_{(QCG)} - V_{(QCAT)} > V_{QCOAMAX}$ 1502000Intro $I_{(REG)}$ Voltage regulated across $R_{(SNS)}$ Accuracy $V_{(REG)} = \frac{1V}{RSET1} \times 1000$ , Programmad Where S AG S RSET 1 to AG, Select RSET1 to program Vasce. 	Current Re	egulation - Fast Charge	· · · · · · · · · · · · · · · · · · ·				
VinesVoltage regulated across $R_{(SNS)}$ Accuracy $V_{IREG}$ $V_{IREG} = \frac{1V}{RSETI} \times 1000,$ $Programmed WhereProgrammed Wher$	OCHARGE	Output current range of converter	$V_{LOWV} \le V_{I(BAT)} < V_{OREG},$ $V_{(VCC)} - V_{I(BAT)} > V_{(DO-MAX)}$	150		2000	mA
ViescVoltage regulated across $R_{(SNS)}$ AccuracyProgrammed Whee S KG $\leq$ RSET1 $\leq$ 10 kQ, Select RSET1 to $V_{REG/messured} = loc_{14ARGE} + R_{NS}$ $(-10\% to 10\% excludes errors due to RSET1and R_{NS} tolerances)-10\%10\%/(IsET1)Output current set voltageV_{(LCO)} \leq V_{(IsAT)} \leq V_{O(REG)},V_{(VCC)} \leq V_{(IsAT)} + V_{O(OMAX)}1000V/IPrecharge to fast-charge transition voltagetransition,Department for precharge to fast chargetransition,Rising voltage:tase: t_{ALL} = 100 ns, 2-mV overdrivetase: t_{ALL} = 100 ms, 2-mV overdrivetase: t_{ALL} = 100 mV,V_{(REG)}200 30 40 msI_{(COV)}V_{(RAT)} < V_{(COV)}, t < t_{REG-PRE} tase: t_{ALL} = 100 ms, 2-mV overdrivetase: t_{ALL} = 100 ms, 2-mV overdrivetase: t_{ALL$							
S KG S RSET1 5 10 KD, Select RSET1 to program Viges, Viges(measured = locxARGE + Rsss (-10% to 10% excludes errors due to RSET1 and R <sub>(SNS)</sub> tolerances)1VViseT1)Output current set voltageV(cow S Viges) SvoreGo), V(co) S Viges1 VigocMAX)1000V//Precharge and Short-Circuit Current RegulationV(cow S Viges1) V(cocMAX)1000V//Precharge to fast-charge transition voltage threshold, BAT, voc) Sviges1, VigocMAX)66871.4759%VorVLOWVPrecharge to fast-charge transition voltage threshold, BAT, toxic)Rising voltage: transition, transition, VigocMAX)203040mmIoperacidaPrecharge to fast-charge transition voltage threshold, BAT, toxic)Rising voltage: transition, toxic) V (igAT) < V(cow), t < toxic toxic			$V_{IREG} = \frac{1V}{RSET1} \times 1000,$				
V(ISETI)       Output current set voltage $V_{LOW} \le V_{I(BAT)} \le V_{O(REG)}, V_{V(CC)} \le V_{I(BAT)} \le V_{O(C)} \le V_{O(C)} \le V_{O(C)} \le V_{$	V <sub>IREG</sub>	Voltage regulated across R <sub>(SNS)</sub> Accuracy	$ \begin{array}{l} 5 \ k \tilde{\Omega} \leq RSET1 \leq 10 \ k \Omega, \ Select \ RSET1 \ to \\ program \ V_{IREG}, \\ V_{IREG(measured)} = I_{OCHARGE} + R_{SNS} \\ (-10\% \ to \ 10\% \ excludes \ errors \ due \ to \ RSET1 \end{array} $	-10%		10%	
K(ISET)Output current set factor $V_{LOWY} \le V_{(IBAT)} < V_{O(REG)}$ $V_{(VCC)} \le V_{(IBAT)} + V(DO-MAX)$ 1000 $V//V_{IACC}$ Precharge and Short-Circuit Current Regulation $V_{O(REG)} + V(DO-MAX)$ 6871.475 $V_{O(RC)}$ Precharge to fast-charge transition voltage threshold, BAT, bq24100/03/03/04/05/08/09 ICs onlyRising voltage: transition,203040mmQoreccurrent equitact time for precharge to fast charge transition,Rising voltage: transition,203040mmQoreccurrent set ransition,Precharge rangeV(BAT) < VLOWV, 1 < tereCHG	V <sub>(ISET1)</sub>	Output current set voltage	$V_{(LOWV)} \le V_{I(BAT)} \le V_{O(REG)},$		1		V
Precharge and Short-Circuit Current Regulation $V_{LOWV}$ Precharge to fast-charge transition voltage threshold, BAT, bq24100/303/04/05/08/09 ICs only       68       71.4       75       %V <sub>Q</sub> t       Deglitch time for precharge to fast charge transition, lgaT, explain threshold, BAT, three transition, three transition three transition three transition three transition three termination detection range to three termination accuracy       VI(BAT) > VRCH       100       m/V         VIREG-PRE       Charge termination detection range to three transition three transination threacuracy       VI(BAT) > VRCH	K <sub>(ISET1)</sub>	Output current set factor	$V_{LOWV} \le V_{I(BAT)} < V_{O(REG)},$		1000		V/A
$V_{LOWV}$ bq24100/03/03A/04/05/08/09 ICs onlyRising voltage: transition, <br< td=""><td>Precharge</td><td>and Short-Circuit Current Regulation</td><td></td><td></td><td></td><td></td><td></td></br<>	Precharge	and Short-Circuit Current Regulation					
LetDeglitch time for precharge to fast charge transition,Rising voltage; transition,203040OPRECHGPrecharge range $V_{I(BAT)} < V_{LOWV}$ , t < there there is the thermal state is the transition,	V <sub>LOWV</sub>	threshold, BAT,		68	71.4	75	%V <sub>O(REG</sub>
OpeRecHGPrecharge range $V_{I(BAT)} < V_{LOWV}$ , t < tprecHG15200m/d $V_{(ISET2)}$ Precharge set voltage, ISET2 $V_{I(BAT)} < V_{LOWV}$ , t < tprecHG	t		Rising voltage; t <sub>RISE</sub> , t <sub>FALL</sub> = 100 ns, 2-mV overdrive	20	30	40	ms
Charge Termination (Current Taper) DetectionVI(BAT) > VRCH15200Market Charge termination detection set voltage, ISET2VI(BAT) > VRCH100V//Market Charge termination accuracyVI(BAT) > VRCH100V//Market Charge termination accuracyVI(BAT) > VRCH1520%Market Charge termination accuracyVI(BAT) > VRCH1520%Market Charge termination accuracyVI(BAT) > VRCH100V//Market Charge termination accuracyVI(BAT) > VRCH100V//Market Termination accuracyVI(BAT) > VRCH20%20%Market Termination accuracyVI(BAT) > VRCH100M/Market Termination accuracyVI(BAT) > VRCH20%20%Market Termination accuracyVI(BAT) > VRCH20%20%Market Termination accuracyVI(BAT) > VRCH20%20%Market Termination accuracyVI(BAT) > VRCH20%20%Market Termination accuracyVI(BAT) > VRCH20%20%	OPRECHG	Precharge range		15		200	mA
Charge Termination (Current Taper) DetectionVI(BAT) > VRCH15200Charge termination detection set voltage, ISET2VI(BAT) > VRCHVI(BAT) > VRCH100V//VIREG.PRE $= 0.1V$ RSET2 × 1000, (PGM) Where 1.2 kΩ ≤ RSET2 ≤ 10 kΩ, Select RSET1 to program VIREG.REF. VIREG.REF. VIREG.REF. VIREG.REF. VIREG.REF. $-20\%$ $20\%$ Charge termination (Current Taper) Detection $V_{I(BAT)} > V_{RCH}$ 15 $200$ Term.Charge termination detection set voltage, ISET2 $V_{I(BAT)} > V_{RCH}$ $100$ $m/$ VIREG.Termination current set factor $V_{I(BAT)} > V_{RCH}$ $20\%$ $20\%$ Charge termination accuracy $V_{I(BAT)} > V_{RCH}$ $20\%$ $20\%$ Charge termination accuracy $V_{I(BAT)} > V_{RCH}$ $20\%$ $20\%$	V <sub>(ISET2)</sub>	Precharge set voltage, ISET2	$V_{I(BAT)} < V_{LOWV}, t < t_{PRECHG}$		100		mV
$ \frac{100 \text{ mV} \leq V_{\text{IREG-PRE}} \leq 100 \text{ mV},}{V_{\text{IREG-PRE}} \leq 100 \text{ mV},} \\ V_{\text{IREG-PRE}}  Voltage \text{ regulated across } R_{\text{SNS}}\text{-Accuracy} \\ \frac{V_{\text{IREG-PRE}} = \frac{0.1 \text{V}}{\text{RSET2}} \times 1000,}{(\text{PGM}) \text{ Where}} \\ \frac{1.2 \text{ k}\Omega \leq \text{RSET2} \leq 10 \text{ k}\Omega, \text{ Select } \text{RSET1}}{\text{ to program } V_{\text{IREG-PRE}}} \\ \frac{-20\%}{20\%} \\ \frac{20\%}{20\%} \\ \frac{1.2 \text{ k}\Omega \leq \text{RSET2} \leq 10 \text{ k}\Omega, \text{ Select } \text{RSET1}}{\text{ to program } V_{\text{IREG-PRE}}} \\ \frac{-20\%}{20\%} \\ \frac{100 \text{ mV} \leq V_{\text{IREG-PRE}}}{(-20\% \text{ to } 20\% \text{ excludes errors due to } \text{RSET1}} \\ \frac{100 \text{ mV} \leq V_{\text{IREG-PRE}}}{\text{ remination (Current Taper) Detection}} \\ \frac{100 \text{ mV} \leq V_{\text{IREG-PRE}}}{\text{ remination detection set voltage,}} \\ \frac{V_{\text{I(BAT)}} > V_{\text{RCH}}}{V_{\text{I(BAT)}} > V_{\text{RCH}}} \\ \frac{100 \text{ mV} \leq V_{\text{I(BAT)}} > V_{\text{RCH}}}{100} \\ \frac{1000 \text{ mV}}{\text{ Charge termination accuracy}} \\ \frac{V_{\text{I(BAT)}} > V_{\text{RCH}}}{V_{\text{I(BAT)}} > V_{\text{RCH}}} \\ \frac{20\%}{20\%} \\ \frac{20\%}{20\%} \\ \frac{1000 \text{ mV}}{20\%} \\$	( )	Precharge current set factor			1000		V/A
$T_{TERM}$ Charge current termination detection range $V_{I(BAT)} > V_{RCH}$ 15       200       m/ $V_{TERM}$ Charge termination detection set voltage, ISET2 $V_{I(BAT)} > V_{RCH}$ 100       m/ $V_{TERM}$ Termination current set factor       100       V//         Charge termination accuracy $V_{I(BAT)} > V_{RCH}$ 20%       20%         Example       Deglitch time for charge termination       Both rising and falling,       20       30       40       mm		Voltage regulated across R <sub>SNS</sub> -Accuracy	$V_{IREG - PRE} = \frac{0.1V}{RSET2} \times 1000,$ (PGM) Where 1.2 k\Omega < RSET2 < 10 k\Omega, Select RSET1 to program V <sub>IREG-PRE</sub> , V <sub>IREG-PRE</sub> (Measured) = I <sub>OPRE-CHG</sub> × R <sub>SNS</sub> (-20% to 20% excludes errors due to RSET1	-20%		20%	
VIERM       Charge termination detection set voltage, ISET2       VI(BAT) > VRCH       100       mV         K(ISET2)       Termination current set factor       1000       V///         Charge termination accuracy       VI(BAT) > VRCH       1000       V//         Charge termination accuracy       VI(BAT) > VRCH       -20%       20%         to reput       Deglitch time for charge termination       Both rising and falling,       20       30       40       mm	Charge Te	rmination (Current Taper) Detection					
VTERM     ISET2     VI(BAT) > VRCH     TOU     MV       K(ISET2)     Termination current set factor     1000     V//       Charger termination accuracy     VI(BAT) > VRCH     -20%     20%       turnerout     Deglitch time for charge termination     Both rising and falling,     20     30     40     mm	ITERM	Charge current termination detection range	V <sub>I(BAT)</sub> > V <sub>RCH</sub>	15		200	mA
Charger termination accuracy $V_{I(BAT)} > V_{RCH}$ -20%20%turnowDeglitch time for charge terminationBoth rising and falling,203040	V <sub>TERM</sub>		$V_{I(BAT)} > V_{RCH}$		100		mV
Charger termination accuracy $V_{I(BAT)} > V_{RCH}$ -20%20%Deditch time for charge terminationBoth rising and falling,203040	K(ISET2)	Termination current set factor			1000		V/A
		Charger termination accuracy	V <sub>I(BAT)</sub> > V <sub>RCH</sub>	-20%		20%	
	dg-TERM	Deglitch time for charge termination		20	30	40	ms

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## bq24105-Q1

TEXAS INSTRUMENTS

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### **ELECTRICAL CHARACTERISTICS (continued)**

#### $T_J = 0^{\circ}C$ to 125°C and recommended supply voltage range (unless otherwise stated)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
% <sub>LTF</sub>	Cold temperature threshold, TS, % of bias	$V_{LTF} = V_{O(VTSB)} \times \% LTF/100$	72.8%	73.5%	74.2%	
% <sub>HTF</sub>	Hot temperature threshold, TS, % of bias	V <sub>HTF</sub> = V <sub>O(VTSB)</sub> × % HTF/100	33.7%	34.4%	35.1%	
% <sub>TCO</sub>	Cutoff temperature threshold, TS, % of bias	V <sub>TCO</sub> = V <sub>O(VTSB)</sub> × % TCO/100	28.7%	29.3%	29.9%	
	LTF hysteresis		0.5%	1%	1.5%	
t <sub>dg-TS</sub>	Deglitch time for temperature fault, TS	Both rising and falling, 2-mV overdrive t <sub>RISE</sub> , t <sub>FALL</sub> = 100 ns	20	30	40	ms
V <sub>O(VTSB)</sub>	TS bias output voltage			3.15		V
V <sub>O(VTSB)</sub>	TS bias voltage regulation accuracy		-10%		10%	
Battery Re	charge Threshold					
V <sub>RCH</sub>	Recharge threshold voltage	Below V <sub>OREG</sub>	75	100	125	mV/cell
t <sub>dg-RCH</sub>	Deglitch time	$V_{I(BAT)}$ < decreasing below threshold, t <sub>FALL</sub> = 100 ns 10-mV overdrive	20	30	40	ms
Stat1, Stat	2, and PG Outputs					
V <sub>OL(STATx)</sub>	Low-level output saturation voltage, STATx	I <sub>O</sub> = 5 mA			0.5	N
V <sub>OL(PG)</sub>	Low-level output saturation voltage, PG	I <sub>O</sub> = 10 mA			0.1	V
CE Input						
VIL	Low-level input voltage	$I_{IL} = 5 \ \mu A$	0		0.4	V
VIH	High-level input voltage	I <sub>IH</sub> = 20 μA	1.3		V <sub>CC</sub>	v
TTC Input						
t <sub>PRECHG</sub>	Precharge timer		1440	1800	2160	s
t <sub>CHARGE</sub>	Programmable charge timer range	$t_{(CHG)} = C_{(TTC)} \times K_{(TTC)}$	25		572	minutes
	Charge timer accuracy	$0.01 \ \mu F \le C_{(TTC)} \le 0.18 \ \mu F$	-10%		10%	
K <sub>TTC</sub>	Timer multiplier			2.6		min/nF
C <sub>TTC</sub>	Charge time capacitor range		0.01		0.22	μF
V <sub>TTC_EN</sub>	TTC enable threshold voltage	V <sub>(TTC)</sub> rising		200		mV



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### **ELECTRICAL CHARACTERISTICS (continued)**

 $T_J = 0^{\circ}C$  to 125°C and recommended supply voltage range (unless otherwise stated)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Sleep Con	nparator					
V	Sleep-mode entry threshold	2.3 V $\leq$ V <sub>I(OUT)</sub> $\leq$ V <sub>OREG</sub> , for 1 or 2 cells	V <sub>CC</sub> ≤ V <sub>IBAT</sub> +5 mV		V <sub>CC</sub> ≤V <sub>IBAT</sub> +75 mV	V
V <sub>SLP-ENT</sub>		$V_{I(OUT)} = 12.6 \text{ V}, \text{ R}_{IN} = 1 \text{ k}\Omega$ bq24105/15 <sup>(1)</sup>	V <sub>CC</sub> ≤ V <sub>IBAT</sub> -4 mV		V <sub>CC</sub> ≤V <sub>IBAT</sub> +73 mV	v
V <sub>SLP-EXIT</sub>	Sleep-mode exit hysteresis,	$2.3 \text{ V} \leq \text{V}_{I(OUT)} \leq \text{V}_{OREG}$	40		160	mV
	Destination (an dass and	$V_{CC}$ decreasing below threshold, t <sub>FALL</sub> = 100 ns, 10-mV overdrive, PMOS turns off		5		μs
t <sub>dg-SLP</sub>	Deglitch time for sleep mode	$V_{CC}$ decreasing below threshold, t <sub>FALL</sub> = 100 ns, 10-mV overdrive, STATx pins turn off	20	30	40	ms
UVLO			•			
V <sub>UVLO-ON</sub>	IC active threshold voltage	V <sub>CC</sub> rising	3.15	3.30	3.50	V
	IC active hysteresis	V <sub>CC</sub> falling	120	150		mV
PWM		<u> </u>	1			
		$7 \text{ V} \le \text{V}_{\text{CC}} \le \text{V}_{\text{CC}(\text{max})}$			400	
	Internal P-channel MOSFET on-resistance	$4.5 \text{ V} \le \text{V}_{\text{CC}} \le 7 \text{ V}$			500	
		$7 \text{ V} \le \text{V}_{\text{CC}} \le \text{V}_{\text{CC(max)}}$			130	mΩ
	Internal N-channel MOSFET on-resistance	$4.5 \text{ V} \le \text{V}_{\text{CC}} \le 7 \text{ V}$			150	
f <sub>OSC</sub>	Oscillator frequency			1.1	100	MHz
USC	Frequency accuracy		-9%	1.1	9%	IVII IZ
	Maximum duty cycle		570		100%	
D <sub>MAX</sub>			00/		100 /6	
D <sub>MIN</sub>	Minimum duty cycle		0%	00		
t <sub>TOD</sub>	Switching delay time (turn on)			20		ns
t <sub>syncmin</sub>	Minimum synchronous FET on time			60		ns
	Synchronous FET minimum current-off threshold <sup>(2)</sup>		50		400	mA
Battery De	etection					
IDETECT	Battery detection current during time-out fault	$V_{I(BAT)} < V_{OREG} - V_{RCH}$		2		mA
IDISCHRG1	Discharge current	V <sub>SHORT</sub> < V <sub>I(BAT)</sub> < V <sub>OREG</sub> - V <sub>RCH</sub>		400		μA
t <sub>DISCHRG1</sub>	Discharge time	V <sub>SHORT</sub> < V <sub>I(BAT)</sub> < V <sub>OREG</sub> - V <sub>RCH</sub>		1		s
WAKE	Wake current	V <sub>SHORT</sub> < V <sub>I(BAT)</sub> < V <sub>OREG</sub> - V <sub>RCH</sub>		2		mA
twake	Wake time	V <sub>SHORT</sub> < V <sub>I(BAT)</sub> < V <sub>OREG</sub> - V <sub>RCH</sub>		0.5		s
I <sub>DISCHRG2</sub>	Termination discharge current	Begins after termination detected, V <sub>I(BAT)</sub> ≤ V <sub>OREG</sub>		400		μA
t <sub>DISCHRG2</sub>	Termination time			262		ms
Output Ca	pacitor		1		I	
C <sub>OUT</sub>	Required output ceramic capacitor range from SNS to PGND, between inductor and R <sub>SNS</sub>		4.7	10	47	μF
C <sub>SNS</sub>	Required SNS capacitor (ceramic) at SNS pin			0.1		μF
Protection	l .					
V <sub>OVP</sub>	OVP threshold voltage	Threshold over $V_{OREG}$ to turn off P-channel MOSFET, STAT1, and STAT2 during charge or termination states	110	117	121	%V <sub>O(REG</sub>
I <sub>LIMIT</sub>	Cycle-by-cycle current limit		2.6	3.6	4.5	А
V <sub>SHORT</sub>	Short-circuit voltage threshold, BAT	V <sub>I(BAT)</sub> falling	1.95	2	2.05	V/cell
ISHORT	Short-circuit current	V <sub>I(BAT)</sub> ≤ V <sub>SHORT</sub>	35		65	mA
T <sub>SHTDWN</sub>	Thermal trip			165		°C
-	Thermal hysteresis			10		°C

(1) For bq24105 and bq24115 only. R<sub>IN</sub> is connected between IN and PGND pins and needed to ensure sleep entry.

(2) N-channel always turns on for ~60 ns and then turns off if current is too low.

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TERMINAL FUNCTIONS

TERMINAL		I/O	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
BAT	14	Ι	Battery voltage sense input. Bypass it with a 0.1 $\mu F$ capacitor to PGND if there are long inductive leads to battery.
CE	16	Ι	Charger enable input. This active low input, if set high, suspends charge and places the device in the low-power sleep mode. Do not pull up this input to VTSB.
FB	13	Ι	Output voltage analog feedback adjustment. Connect the output of a resistive voltage divider powered from the battery terminals to this node to adjust the output battery voltage regulation.
IN	3, 4	Ι	Charger input voltage.
ISET1	8	I/O	Charger current set point 1 (fast charge). Use a resistor to ground to set this value.
ISET2	9	I/O	Charge current set point 2 (precharge and termination), set by a resistor connected to ground.
OUT	1, 20	0	Charge current output inductor connection. Connect a zener TVS diode between OUT pin and PGND pin to clamp the voltage spike to protect the power MOSFETs during abnormal conditions.
PG	5	0	Power-good status out <u>put</u> (open drain). The transistor turns on when a valid $V_{CC}$ is detected. It is turned off in the sleep mode. PG can be used to drive a LED or communicate with a host processor.
PGND	17,18		Power ground input
SNS	15	Ι	Charge current-sense input. Battery current is sensed via the voltage drop developed on this pin by an external sense resistor in series with the battery pack. A 0.1- $\mu$ F capacitor to PGND is required.
STAT1	2	0	Charge status 1 (open-drain output). When the transistor turns on indicates charge in process. When it is off and with the condition of STAT2 indicates various charger conditions (see Table 1).
STAT2	19	0	Charge status 2 (open-drain output). When the transistor turns on indicates charge is done. When it is off and with the condition of STAT1 indicates various charger conditions (see Table 1).
TS	12	I	Temperature sense input. This input monitors its voltage against an internal threshold to determine if charging is allowed. Use an NTC thermistor and a voltage divider powered from VTSB to develop this voltage (see Figure 6).
ттс	7	Ι	Timer and termination control. Connect a capacitor from this node to GND to set the bqSWITCHER timer. When this input is low, the timer and termination detection are disabled.
VCC	6	Ι	Analog device input. A 0.1-µF capacitor to VSS is required.
VSS	10		Analog ground input
VTSB	11	0	TS internal bias regulator voltage. Connect capacitor (with a value between a $0.1\mbox{-}\mu F$ and $1\mbox{-}\mu F)$ between this output and VSS.
Exposed Thermal Pad	Pad		There is an internal electrical connection between the exposed thermal pad and VSS. The exposed thermal pad must be connected to the same potential as the VSS pin on the printed circuit board. The power pad can be used as a <i>star</i> ground connection between V <sub>SS</sub> and PGND. A common ground plane may be used. VSS pin must be connected to ground at all times.

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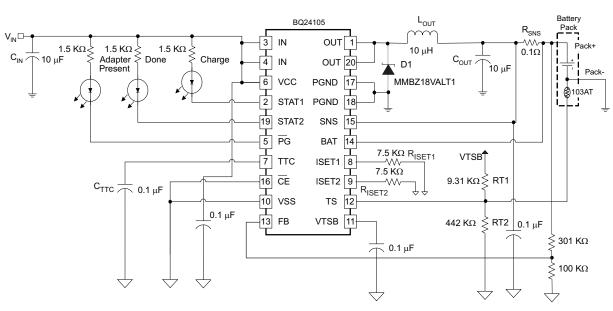
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**TYPICAL APPLICATION CIRCUIT** 

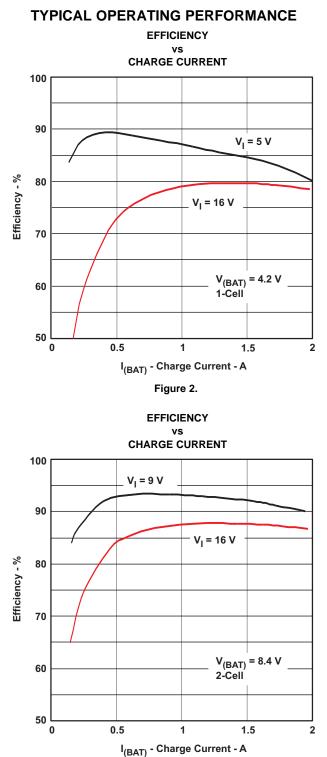
Figure 1. Stand-Alone 2-Cell Application



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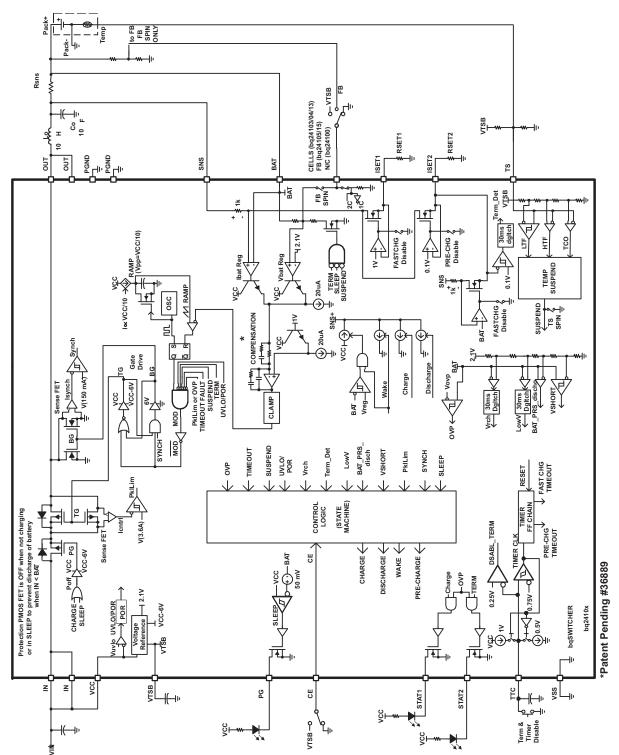


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FUNCTIONAL BLOCK DIAGRAM





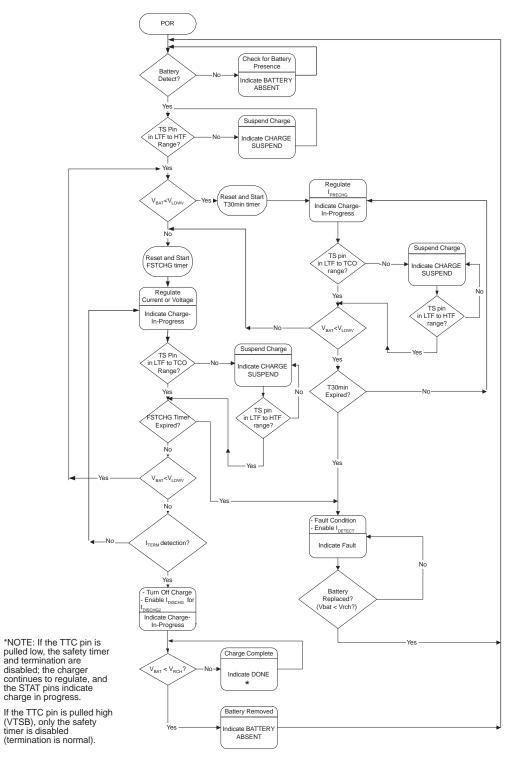
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### **OPERATIONAL FLOW CHART**







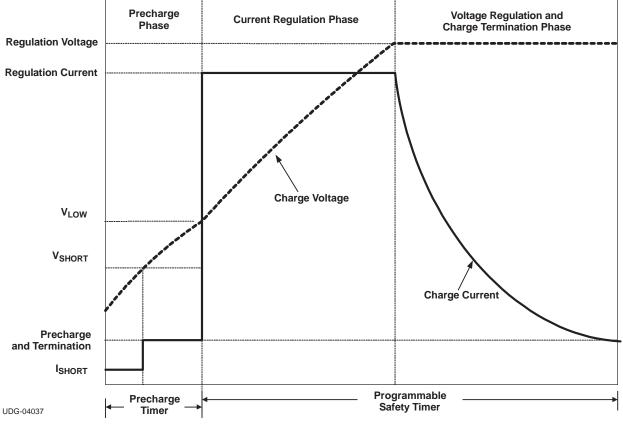
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### DETAILED DESCRIPTION

The bqSWITCHER<sup>™</sup> supports a precision Li-ion or Li-polymer charging system for one-, two-, or three-cell applications. See Figure 4 for a typical charge profile.





#### **PWM Controller**

The bq24105 provides an integrated fixed 1MHz frequency voltage-mode controller with Feed-Forward function to regulate charge current or voltage. This type of controller is used to help improve line transient response, thereby simplifying the compensation network used for both continuous and discontinuous current conduction operation. The voltage and current loops are internally compensated using a Type-III compensation scheme that provides enough phase boost for stable operation, allowing the use of small ceramic capacitors with very low ESR. There is a 0.5-V offset on the bottom of the PWM ramp to allow the device to operate between 0% to 100% duty cycle.

The internal PWM gate drive can directly control the internal PMOS and NMOS power MOSFETs. The high-side gate voltage swings from  $V_{CC}$  (when off), to  $V_{CC} - 6$  (when on and  $V_{CC}$  is greater than 6 V) to help reduce the conduction losses of the converter by enhancing the gate an extra volt beyond the standard 5V. The low-side gate voltage swings from 6 V, to turn on the NMOS, down to PGND to turn it off. The bq24105 has two back to back common-drain P-MOSFETs on the high side. An input P-MOSFET prevents battery discharge when IN is lower than BAT. The second P-MOSFET behaves as the switching control FET, eliminating the need of a bootstrap capacitor.

Cycle-by-cycle current limit is sensed through the internal high-side sense FET. The threshold is set to a nominal 3.6A peak current. The low-side FET also has a current limit that decides if the PWM Controller will operate in synchronous or non-synchronous mode. This threshold is set to 100mA and it turns off the low-side NMOS before the current reverses, preventing the battery from discharging. Synchronous operation is used when the current of the low-side FET is greater than 100mA to minimize power losses.

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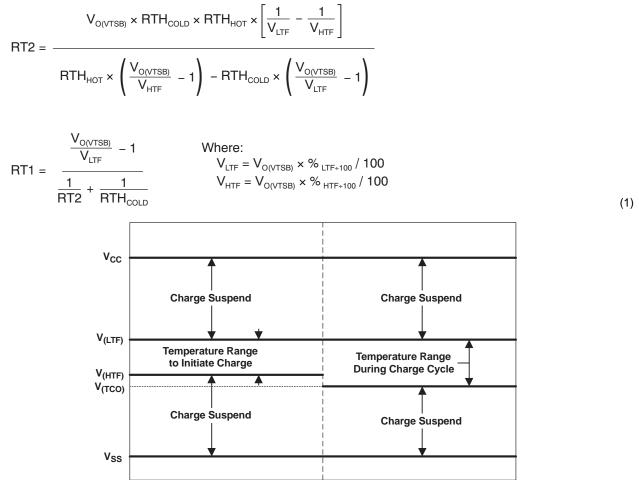
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#### **Temperature Qualification**

The bqSWITCHER continuously monitors battery temperature by measuring the voltage between the TS pin and VSS pin. A negative temperature coefficient thermistor (NTC) and an external voltage divider typically develop this voltage. The bqSWITCHER compares this voltage against its internal thresholds to determine if charging is allowed. To initiate a charge cycle, the battery temperature must be within the  $V_{(LTF)}$ -to- $V_{(HTF)}$  thresholds. If battery temperature is outside of this range, the bqSWITCHER suspends charge and waits until the battery temperature must be within the  $V_{(LTF)}$ -to- $V_{(HTF)}$  range. During the charge cycle (both precharge and fast charge), the battery temperature must be within the  $V_{(LTF)}$ -to- $V_{(TCO)}$  thresholds. If battery temperature is outside of this range, the bqSWITCHER suspends charge and fast charge), the bqSWITCHER suspends charge and waits until the battery temperature is outside of this range. The bqSWITCHER suspends charge by turning off the PWM and holding the timer value (i.e., timers are not reset during a suspend condition). Note that the bias for the external resistor divider is provided from the VTSB output. Applying a constant voltage between the  $V_{(LTF)}$ -to- $V_{(HTF)}$  thresholds to the TS pin disables the temperature-sensing feature.





### **Battery Preconditioning (Precharge)**

On power up, if the battery voltage is below the  $V_{LOWV}$  threshold, the bqSWITCHER applies a precharge current,  $I_{PRECHG}$ , to the battery. This feature revives deeply discharged cells. The bqSWITCHER activates a safety timer,  $t_{PRECHG}$ , during the conditioning phase. If the  $V_{LOWV}$  threshold is not reached within the timer period, the bqSWITCHER turns off the charger and enunciates FAULT on the STATx pins. In the case of a FAULT condition, the bqSWITCHER reduces the current to  $I_{DETECT}$ .  $I_{DETECT}$  is used to detect a battery replacement condition. Fault condition is cleared by POR or battery replacement.



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The magnitude of the precharge current,  $I_{O(PRECHG)}$ , is determined by the value of programming resistor,  $R_{(ISET2)}$ , connected to the ISET2 pin.

$$I_{O(PRECHG)} = \frac{K_{(ISET2)} \times V_{(ISET2)}}{\left(R_{(ISET2)} \times R_{(SNS)}\right)}$$

where

R<sub>SNS</sub> is the external current-sense resistor

V<sub>(ISET2)</sub> is the output voltage of the ISET2 pin

K<sub>(ISET2)</sub> is the V/A gain factor

V(ISET2) and K(ISET2) are specified in the Electrical Characteristics table.

### **Battery Charge Current**

The battery charge current,  $I_{O(CHARGE)}$ , is established by setting the external sense resistor,  $R_{(SNS)}$ , and the resistor,  $R_{(ISET1)}$ , connected to the ISET1 pin.

In order to set the current, first choose  $R_{(SNS)}$  based on the regulation threshold  $V_{IREG}$  across this resistor. The best accuracy is achieved when the  $V_{IREG}$  is between 100 mV and 200 mV.

$$R_{(SNS)} = \frac{V_{IREG}}{I_{OCHARGE}}$$
(3)

If the results is not a standard sense resistor value, choose the next larger value. Using the selected standard value, solve for  $V_{IREG}$ . Once the sense resistor is selected, the ISET1 resistor can be calculated using the following equation:

$$R_{ISET1} = \frac{K_{ISET1} \times V_{ISET1}}{R_{SNS} \times I_{CHARGE}}$$

#### **Battery Voltage Regulation**

The voltage regulation feedback occurs through the BAT pin. This input is tied directly to the positive side of the battery pack. The bqSWITCHER monitors the battery-pack voltage between the BAT and VSS pins.

Output regulation voltage is specified as:

$VOREG = \frac{(R1 + R2)}{R2} \times VIBAT$		
R2	(5	)

where R1 and R2 are resistor divider from BAT to FB and FB to VSS, respectively.

Recharge threshold voltage is specified as:

$V_{PCH} = \frac{(R1 + R2)}{(R1 + R2)}$	
• <sub>RCH</sub> – R2 x 50 mV	(6)



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#### **Charge Termination and Recharge**

The bqSWITCHER monitors the charging current during the voltage regulation phase. Once the termination threshold,  $I_{TERM}$ , is detected, the bqSWITCHER terminates charge. The termination current level is selected by the value of programming resistor,  $R_{(ISET2)}$ , connected to the ISET2 pin.

$$I_{\text{TERM}} = \frac{K_{(\text{ISET2})} \times V_{\text{TERM}}}{\left(R_{(\text{ISET2})} \times R_{(\text{SNS})}\right)}$$

where

R<sub>(SNS)</sub> is the external current-sense resistor

 $V_{\text{TERM}}$  is the output of the ISET2 pin

 $K_{(ISET2)}$  is the A/V gain factor

V<sub>TERM</sub> and K<sub>(ISET2)</sub> are specified in the Electrical Characteristics table

As a safety backup, the bqSWITCHER also provides a programmable charge timer. The charge time is programmed by the value of a capacitor connected between the TTC pin and GND by the following formula:

 $t_{CHARGE} = C_{(TTC)} \times K_{(TTC)}$ 

where

 $C_{(\ensuremath{\mathsf{TTC}})}$  is the capacitor connected to the TTC pin

K(TTC) is the multiplier

A new charge cycle is initiated when one of the following conditions is detected:

- The battery voltage falls below the V<sub>RCH</sub> threshold.
- Power-on reset (POR), if battery voltage is below the V<sub>RCH</sub> threshold
- CE toggle
- TTC pin, described as follows.

In order to disable the charge termination and safety timer, the user can pull the TTC input below the  $V_{TTC_EN}$  threshold. Going above this threshold enables the termination and safety timer features and also resets the timer. Tying TTC high disables the safety timer only.



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#### **Sleep Mode**

The bqSWITCHER enters the low-power sleep mode if the VCC pin is removed from the circuit. This feature prevents draining the battery during the absence of VCC.

#### Charge Status Outputs

The open-drain STAT1 and STAT2 outputs indicate various charger operations as shown in Table 1. These status pins can be used to drive LEDs or communicate to the host processor. Note that OFF indicates that the open-drain transistor is turned off.

#### Table 1. Status Pins Summary

Charge State	STAT1	STAT2
Charge-in-progress	ON	OFF
Charge complete	OFF	ON
Charge suspend, timer fault, overvoltage, sleep mode, battery absent	OFF	OFF

#### Table 2. Status Pins Summary

Charge State	STAT1	STAT2
Battery absent	OFF	OFF
Charge-in-progress	ON	OFF
Charge complete	OFF	ON
Battery over discharge, V <sub>I(BAT)</sub> < V <sub>(SC)</sub>	ON/OFF (0.5 Hz)	OFF
Charge suspend (due to TS pin and internal thermal protection)	ON/OFF (0.5 Hz)	OFF
Precharge timer fault	ON/OFF (0.5 Hz)	OFF
Fast charge timer fault	ON/OFF (0.5 Hz)	OFF
Sleep mode	OFF	OFF

## **PG** Output

The open-drain  $\overline{PG}$  (power good) indicates when the AC-to-DC adapter (i.e., V<sub>CC</sub>) is present. The output turns on when sleep-mode exit threshold, V<sub>SLP-EXIT</sub>, is detected. This output is turned off in the sleep mode. The  $\overline{PG}$  pin can be used to drive an LED or communicate to the host processor.

### **CE** Input (Charge Enable)

The  $\overline{CE}$  digital input is used to disable or enable the charge process. A low-level signal on this pin enables the charge and a high-level V<sub>CC</sub> signal disables the charge. A high-to-low transition on this pin also resets all timers and fault conditions. Note that the  $\overline{CE}$  pin cannot be pulled up to VTSB voltage. This may create power-up issues.



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#### Timer Fault Recovery

As shown in Figure 6, bqSWITCHER provides a recovery method to deal with timer fault conditions. The following summarizes this method.

Condition 1  $V_{I(BAT)}$  above recharge threshold ( $V_{OREG}$  -  $V_{RCH}$ ) and timeout fault occurs.

Recovery method: bqSWITCHER waits for the battery voltage to fall below the recharge threshold. This could happen as a result of a load on the battery, self-discharge or battery removal. Once the battery falls below the recharge threshold, the bqSWITCHER clears the fault and enters the battery absent detection routine. A POR or CE toggle also clears the fault.

Condition 2 Charge voltage below recharge threshold ( $V_{OREG} - V_{RCH}$ ) and timeout fault occurs

Recovery method: Under this scenario, the bqSWITCHER applies the  $I_{DETECT}$  current. This small current is used to detect a battery removal condition and remains on as long as the battery voltage stays below the recharge threshold. If the battery voltage goes above the recharge threshold, then the bqSWITCHER disables the  $I_{DETECT}$  current and executes the recovery method described in Condition 1. Once the battery falls below the recharge threshold, the bqSWITCHER clears the fault and enters the battery absent detection routine. A POR or CE toggle also clears the fault.

#### **Output Overvoltage Protection**

The bqSWITCHER provides a built-in overvoltage protection to protect the device and other components against damages if the battery voltage gets too high, as when the battery is suddenly removed. When an overvoltage condition is detected, this feature turns off the PWM and STATx pins. The fault is cleared once  $V_{IBAT}$  drops to the recharge threshold ( $V_{OREG} - V_{RCH}$ ).

#### Inductor, Capacitor, and Sense Resistor Selection Guidelines

The bqSWITCHER provides internal loop compensation. With this scheme, best stability occurs when LC resonant frequency,  $f_o$  is approximately 16 kHz (8 kHz to 32 kHz). Equation 9 can be used to calculate the value of the output inductor and capacitor. Table 3 provides a summary of typical component values for various charge rates.

$$f_0 = \frac{1}{2\pi \times \sqrt{L_{OUT} \times C_{OUT}}}$$

(9)

Table 3.	Output	Components	Summary
----------	--------	------------	---------

CHARGE CURRENT	0.5 A	1 A	2 A
Output inductor, L <sub>OUT</sub>	22 µH	10 µH	4.7 μH
Output capacitor, C <sub>OUT</sub>	4.7 µF	10 µF	22 $\mu$ F (or 2 × 10 $\mu$ F) ceramic
Sense resistor, R <sub>(SNS)</sub>	0.2 Ω	0.1 Ω	0.05 Ω



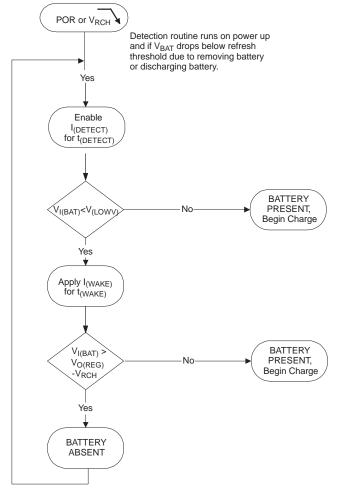
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#### **Battery Detection**

For applications with removable battery packs, bqSWITCHER provides a battery absent detection scheme to reliably detect insertion and/or removal of battery packs.





The voltage at the BAT pin is held above the battery recharge threshold,  $V_{OREG} - V_{RCH}$ , by the charged battery following fast charging. When the voltage at the BAT pin falls to the recharge threshold, either by a load on the battery or due to battery removal, the bqSWITCHER begins a battery absent detection test. This test involves enabling a detection current,  $I_{DISCHARGE1}$ , for a period of  $t_{DISCHARGE1}$  and checking to see if the battery voltage is below the short circuit threshold,  $V_{SHORT}$ . Following this, the wake current,  $I_{WAKE}$  is applied for a period of  $t_{WAKE}$  and the battery voltage is checked again to ensure that it is above the recharge threshold. The purpose of this current is to attempt to *close* an open battery pack protector, if one is connected to the bqSWITCHER.

Passing both of the discharge and charge tests indicates a battery absent fault at the STAT pins. Failure of either test starts a new charge cycle. For the absent battery condition, typically the voltage on the BAT pin rises and falls between 0V and  $V_{OVP}$  thresholds indefinitely.



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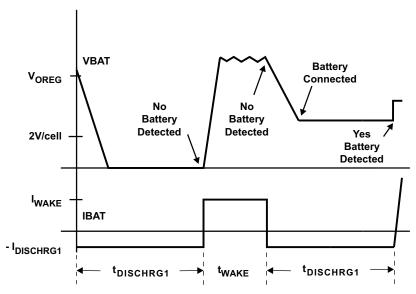


Figure 8. Battery Detect Timing Diagram

#### **Battery Detection Example**

In order to detect a *no battery* condition during the discharge and wake tests, the maximum output capacitance should not exceed the following:

a. Discharge ( $I_{DISCHRG1} = 400 \ \mu A$ ,  $t_{DISCHRG1} = 1$ s,  $V_{SHORT} = 2$ V)

$$C_{MAX\_DIS} = \frac{I_{DISCHRG1} \times I_{DISCHRG1}}{V_{OREG} - V_{SHORT}}$$

$$C_{MAX\_DIS} = \frac{400 \,\mu A \times 1s}{4.2 \,V - 2 \,V}$$

$$C_{MAX\_DIS} = 182 \,\mu F$$
(10)

b. Wake (I<sub>WAKE</sub> = 2 mA,  $t_{WAKE}$  = 0.5 s, V<sub>OREG</sub> - V<sub>RCH</sub> = 4.1V)

$$C_{MAX_WAKE} = \frac{I_{WAKE} \land I_{WAKE}}{\left(V_{OREG} - V_{RCH}\right) - 0 V}$$
$$C_{MAX_WAKE} = \frac{2 \text{ mA} \times 0.5 \text{s}}{(4.2 \text{ V} - 0.1 \text{ V}) - 0 \text{V}}$$
$$C_{MAX_WAKE} = 244 \,\mu\text{F}$$

(11)

Based on these calculations the recommended maximum output capacitance to ensure proper operation of the battery detection scheme is 100  $\mu$ F which will allow for process and temperature variations.

Figure 9 shows the battery detection scheme when a battery is inserted. Channel 3 is the output signal and Channel 4 is the output current. The output signal switches between  $V_{OREG}$  and GND until a battery is inserted. Once the battery is detected, the output current increases from 0A to 1.3A, which is the programmed charge current for this application.



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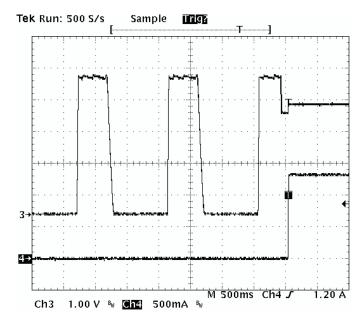


Figure 9. Battery Detection Waveform When a Battery is Inserted

Figure 10 shows the battery detection scheme when a battery is removed. Channel 3 is the output signal and Channel 4 is the output current. When the battery is removed, the output signal goes up due to the stored energy in the inductor and it crosses the  $V_{OREG} - V_{RCH}$  threshold. At this point the output current goes to 0A and the IC terminates the charge process and turns on the  $I_{DISCHG2}$  for  $t_{DISCHG2}$ . This causes the output voltage to fall down below the  $V_{OREG} - V_{RCHG}$  threshold triggering a *Battery Absent* condition and starting the battery detection scheme.

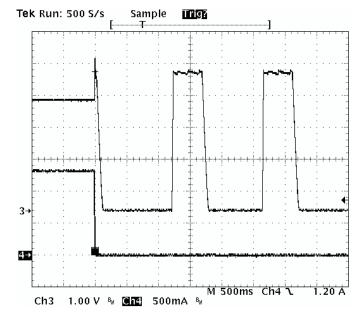


Figure 10. Battery Detection Waveform When a Battery is Removed



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#### **Current Sense Amplifier**

A current sense amplifier feature that translates the charge current into a DC voltage is offered. Figure 11 is a block diagram of this feature.

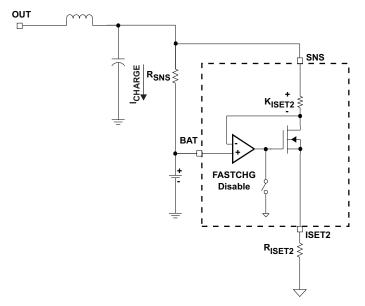


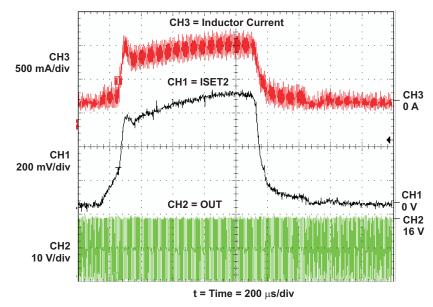
Figure 11. Current Sense Amplifier

The voltage on the ISET2 pin can be used to calculate the charge current. Equation 12 shows the relationship between the ISET2 voltage and the charge current:

$$I_{CHARGE} = \frac{V_{ISET2} \times K_{(ISET2)}}{R_{SNS} \times R_{ISET2}}$$

(12)

This feature can be used to monitor the charge current (Figure 12) during the current regulation phase (Fastcharge only) and the voltage regulation phase. The schematic for the application circuit for this waveform is shown in Figure 14







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## **bqSWITCHER SYSTEM DESIGN EXAMPLE**

The following section provides a detailed system design example for the bq24100.

### System Design Specifications:

- V<sub>IN</sub> = 16V
- V<sub>BAT</sub> = 4.2V (1-Cell)
- I<sub>CHARGE</sub> = 1.33 A
- I<sub>PRECHARGE</sub> = I<sub>TERM</sub> = 133 mA
- Safety Timer = 5 hours
- Inductor Ripple Current = 30% of Fast Charge Current
- Initiate Charge Temperature = 0°C to 45°C
- 1. Determine the inductor value ( $L_{OUT}$ ) for the specified charge current ripple:

 $\Delta I_{L} = I_{CHARGE} \times I_{CHARGE} Ripple$ 

$$L_{OUT} = \frac{V_{BAT} \times (V_{INMAX} - V_{BAT})}{V_{INMAX} \times f \times \Delta I_{L}}$$
$$L_{OUT} = \frac{4.2 \times (16 - 4.2)}{16 \times (1.1 \times 10^{6}) \times (1.33 \times 0.3)}$$

$$L_{OUT} = 7.06 \,\mu\text{H}$$

Set the output inductor to standard 10  $\mu$ H. Calculate the total ripple current with using the 10  $\mu$ H inductor:

$$\Delta I_{L} = \frac{V_{BAT} \times (V_{INMAX} - V_{BAT})}{V_{INMAX} \times f \times L_{OUT}}$$
$$\Delta I_{L} = \frac{4.2 \times (16 - 4.2)}{16 \times (1.1 \times 10^{6}) \times (10 \times 10^{-6})}$$
$$\Delta I_{L} = 0.282 \text{ A}$$
(14)

Calculate the maximum output current (peak current):

$$I_{LPK} = I_{OUT} + \frac{\Delta I_{L}}{2}$$

$$I_{LPK} = 1.33 + \frac{0.282}{2}$$

$$I_{LPK} = 1.471 \text{ A}$$
(15)

Use standard 10 µH inductor with a saturation current higher than 1.471A. (i.e., Sumida CDRH74-100)



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2. Determine the output capacitor value (<sub>OUT</sub>) using 16 kHz as the resonant frequency:

$$f_{0} = \frac{1}{2\pi \sqrt{L_{OUT} \times C_{OUT}}}$$
$$C_{OUT} = \frac{1}{4\pi^{2} \times f_{0}^{2} \times L_{OUT}}$$
$$C_{OUT} = \frac{1}{4\pi^{2} \times (16 \times 10^{3})^{2} \times (10 \times 10^{-6})}$$

$$C_{OUT} = 9.89 \,\mu\text{F}$$

Use standard value 10  $\mu$ F, 25V, X5R, ±20% ceramic capacitor (i.e., Panasonic 1206 ECJ-3YB1E106M 3. Determine the sense resistor using the following equation:

$$R_{SNS} = \frac{V_{RSNS}}{I_{CHARGE}}$$
(17)

In order to get better current regulation accuracy (±10%), let V<sub>RSNS</sub> be between 100 mV and 200 mV. Use  $V_{RSNS} = 100$  mV and calculate the value for the sense resistor.

$$R_{SNS} = \frac{100 \text{ mV}}{1.33 \text{ A}}$$

$$R_{SNS} = 0.075 \Omega$$
(18)

This value is not standard in resistors. If this happens, then choose the next larger value which in this case is 0.1 $\Omega$ . Using the same equation (15) the actual V<sub>RSNS</sub> will be 133mV. Calculate the power dissipation on the sense resistor:

$$P_{RSNS} = I_{CHARGE}^{2} \times R_{SNS}$$

$$P_{RSNS} = 1.33^{2} \times 0.1$$

$$P_{RSNS} = 176.9 \text{ mW}$$
(19)

Select standard value 100 m $\Omega,$  0.25W 0805, 1206 or 2010 size, high precision sensing resistor. (i.e., Vishay CRCW1210-0R10F)

4. Determine ISET 1 resistor using the following equation:

$$R_{ISET1} = \frac{K_{ISET1} \times V_{ISET1}}{R_{SNS} \times I_{CHARGE}}$$
$$R_{ISET1} = \frac{1000 \times 1.0}{0.1 \times 1.33}$$
$$R_{ISET1} = 7.5 \text{ k}\Omega$$

Select standard value 7.5 k $\Omega$ , 1/16W ±1% resistor (i.e., Vishay CRCWD0603-7501-F)

5. Determine ISET 2 resistor using the following equation:

$$R_{ISET2} = \frac{R_{ISET2} \times V_{ISET2}}{R_{SNS} \times I_{PRECHARGE}}$$

$$R_{ISET2} = \frac{1000 \times 0.1}{0.1 \times 0.133}$$

$$R_{ISET2} = 7.5 \text{ k}\Omega$$
(21)

Select standard value 7.5 k $\Omega$ , 1/16W ±1% resistor (i.e., Vishay CRCWD0603-7501-F)



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6. Determine TTC capacitor ( $_{TTC}$ ) for the 5.0 hours safety timer using the following equation:

$$C_{TTC} = \frac{{}^{t}CHARGE}{K_{TTC}}$$
$$C_{TTC} = \frac{300 \text{ m}}{2.6 \text{ m/nF}}$$
$$C_{TTC} = 115.4 \text{ nF}$$

(22)

Select standard value 100 nF, 16V, X7R, ±10% ceramic capacitor (i.e., Panasonic ECJ-1VB1C104K). Using this capacitor the actual safety timer will be 4.3 hours.

7. Determine TS resistor network for an operating temperature range from 0°C to 45°C.

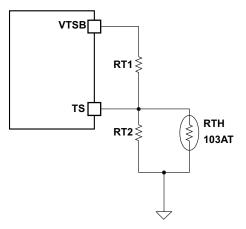


Figure 13. TS Resistor Network

Assuming a 103AT NTC Thermistor on the battery pack, determine the values for RT1 and RT2 using the following equations:

$$RT2 = \frac{V_{O(VTSB)} \times RTH_{COLD} \times RTH_{HOT} \times \left[\frac{1}{V_{LTF}} - \frac{1}{V_{HTF}}\right]}{RTH_{HOT} \times \left(\frac{V_{O(VTSB)}}{V_{HTF}} - 1\right) - RTH_{COLD} \times \left(\frac{V_{O(VTSB)}}{V_{LTF}} - 1\right)}$$

$$RT1 = \frac{\frac{V_{O(VTSB)}}{V_{LTF}} - 1}{\frac{1}{RT2} + \frac{1}{RTH_{COLD}}} \qquad Where: V_{LTF} = V_{O(VTSB)} \times \%_{LTF+100} / 100 V_{HTF} = V_{O(VTSB)} \times \%_{HTF+100} / 100$$

$$RTH_{COLD} = 27.28 \text{ k}\Omega$$

$$RTH_{HOT} = 4.912 \text{ k}\Omega$$

$$RT1 = 9.31 \text{ k}\Omega$$

$$RT2 = 442 \text{ k}\Omega$$
(24)

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**APPLICATION INFORMATION** 

## Charging Battery and Powering System Without Affecting Battery Charge and Termination

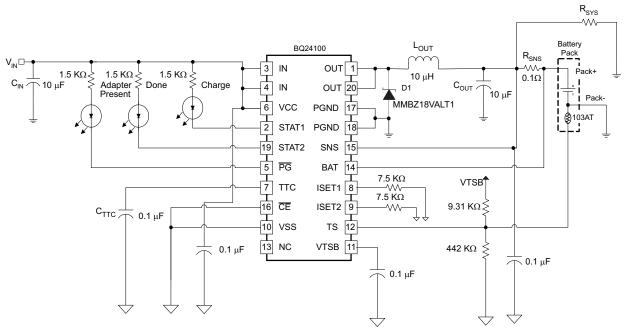


Figure 14. Application Circuit for Charging a Battery and Powering a System Without Affecting Termination

The bqSWITCHER was designed as a stand-alone battery charger but can be easily adapted to power a system load, while considering a few minor issues.

Advantages:

- 1. The charger controller is based only on what current goes through the current-sense resistor (so precharge, constant current, and termination all work well), and is not affected by the system load.
- 2. The input voltage has been converted to a usable system voltage with good efficiency from the input.
- 3. Extra external FETs are not needed to switch power source to the battery.
- 4. The TTC pin can be grounded to disable termination and keep the converter running and the battery fully charged, or let the switcher terminate when the battery is full and then run off of the battery via the sense resistor.

Other Issues:

- If the system load current is large (≥ 1 A), the IR drop across the battery impedance causes the battery voltage to drop below the refresh threshold and start a new charge. The charger would then terminate due to low charge current. Therefore, the charger would cycle between charging and termination. If the load is smaller, the battery would have to discharge down to the refresh threshold resulting in a much slower cycling. Note that grounding the TTC pin keeps the converter on continuously.
- 2. If TTC is grounded, the battery is kept at 4.2 V (not much different than leaving a fully charged battery set unloaded).
- 3. Efficiency declines 2-3% hit when discharging through the sense resistor to the system.



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#### Using bq24105 to Charge LiFePO<sub>4</sub> Battery

The LiFePO<sub>4</sub> battery has many unique features such as a high thermal runaway temperature, discharge current capability, and charge current. These special features make it attractive in many applications such as power tools. The recommended charge voltage is 3.6 V and termination current is 50 mA. Figure 15 shows an application circuit for charging one cell LiFePO4 using bq24105. The charge voltage is 3.6 V and recharge voltage is 3.516 V. The fast charging current is set to 1.33 A while the termination current is 50 mA. This circuit can be easily changed to support two or three cell applications. However, only 84 mV difference between regulation set point and rechargeable threshold makes it frequently enter into recharge mode when small load current is applied. This can be solved by lower down the recharge voltage threshold to 200 mV to discharge more energy from the battery before it enters recharge mode again. See the application report, *Using the* bq24105/25 to Charge LiFePO<sub>4</sub> Battery (SLUA443), for additional details. The recharge threshold should be selected according to real application conditions.

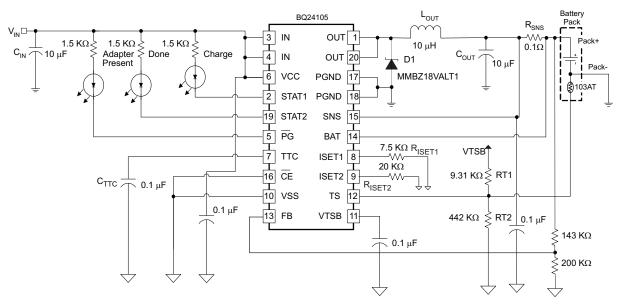


Figure 15. 1-Cell LiFePO4 Application



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## THERMAL CONSIDERATIONS

The SWITCHER is packaged in a thermally enhanced MLP package. The package includes a thermal pad to provide an effective thermal contact between the IC and the printed circuit board (PCB). Full PCB design guidelines for this package are provided in the application report entitled: *QFN/SON PCB Attachment* (SLUA271).

The most common measure of package thermal performance is thermal impedance ( $\theta_{JA}$ ) measured (or modeled) from the chip junction to the air surrounding the package surface (ambient). The mathematical expression for  $\theta_{JA}$  is:

$$\theta_{(JA)} = \frac{\mathsf{T}_{J} - \mathsf{T}_{A}}{\mathsf{P}}$$

(25)

Where:

 $T_J$  = chip junction temperature

T<sub>A</sub> = ambient temperature

P = device power dissipation

Factors that can greatly influence the measurement and calculation of  $\theta_{JA}$  include:

- Whether or not the device is board mounted
- Trace size, composition, thickness, and geometry
- · Orientation of the device (horizontal or vertical)
- · Volume of the ambient air surrounding the device under test and airflow
- · Whether other surfaces are in close proximity to the device being tested

The device power dissipation, P, is a function of the charge rate and the voltage drop across the internal power FET. It can be calculated from the following equation:

 $P = [Vin \times lin - Vbat \times lbat]$ 

Due to the charge profile of Li-xx batteries, the maximum power dissipation is typically seen at the beginning of the charge cycle when the battery voltage is at its lowest. (See Figure 5.)



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## bq24105-Q1

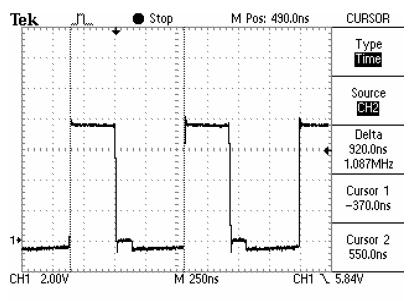
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## PCB LAYOUT CONSIDERATION

It is important to pay special attention to the PCB layout. The following provides some guidelines:

- To obtain optimal performance, the power input capacitors, connected from input to PGND, should be placed as close as possible to the bqSWITCHER. The output inductor should be placed directly above the IC and the output capacitor connected between the inductor and PGND of the IC. The intent is to minimize the current path loop area from the OUT pin through the LC filter and back to the GND pin. The sense resistor should be adjacent to the junction of the inductor and output capacitor. Route the sense leads connected across the R<sub>(SNS)</sub> back to the IC, close to each other (minimize loop area) or on top of each other on adjacent layers (do not route the sense leads through a high-current path). Use an optional capacitor downstream from the sense resistor if long (inductive) battery leads are used.
- Place all small-signal components (C<sub>TTC</sub>, RSET1/2 and TS) close to their respective IC pin (do not place components such that routing interrupts power stage currents). All small *control* signals should be routed away from the high current paths.
- The PCB should have a ground plane (return) connected directly to the return of all components through vias (three vias per capacitor for power-stage capacitors, three vias for the IC PGND, one via per capacitor for small-signal components). A *star* ground design approach is typically used to keep circuit block currents isolated (high-power/low-power small-signal) which reduces noise-coupling and ground-bounce issues. A single ground plane for this design gives good results. With this small layout and a single ground plane, there is not a ground-bounce issue, and having the components segregated minimizes coupling between signals.
- The high-current charge paths into IN and from the OUT pins must be sized appropriately for the maximum charge current in order to avoid voltage drops in these traces. The PGND pins should be connected to the ground plane to return current through the internal low-side FET. The *thermal* vias in the IC PowerPAD<sup>™</sup> provide the return-path connection.
- The bqSWITCHER is packaged in a thermally enhanced MLP package. The package includes a thermal pad
  to provide an effective thermal contact between the IC and the PCB. Full PCB design guidelines for this
  package are provided in the application report entitled: *QFN/SON PCB Attachment* (SLUA271). Six 10-mil to
  13-mil vias are a minimum number of recommended vias, placed in the IC's power pad, connecting it to a
  ground *thermal* plane on the opposite side of the PWB. This plane must be at the same potential as V<sub>SS</sub> and
  PGND of this IC.
- See user guide SLUU200 for an example of good layout.

WAVEFORMS: All waveforms are taken at Lout (IC Out pin).  $V_{IN} = 7.6$  V and the battery was set to 2.6 V, 3.5 V, and 4.2 V for the three waveforms. When the top switch of the converter is *on*, the waveform is at ~7.5 V, and when *off*, the waveform is near ground. Note that the ringing on the switching edges is small. This is due to a *tight* layout (minimized loop areas), a shielded inductor (closed core), and using a low-inductive scope ground lead (i.e., short with minimum loop).





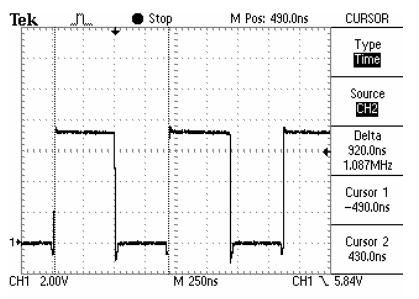
## bq24105-Q1



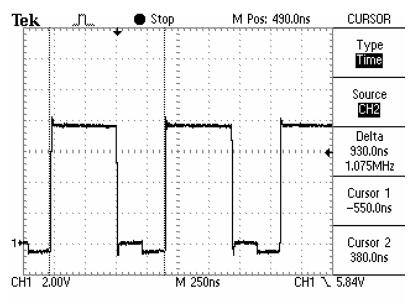
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Precharge: The current is low in precharge; so, the bottom synchronous FET turns off after its minimum on-time which explains the step between  $\neq 0$  V and -0.5 V. When the bottom FET and top FET are off, the current conducts through the body diode of the bottom FET which results in a diode drop below the ground potential. The initial negative spike is the delay turning on the bottom FET, which is to prevent shoot-through current as the top FET is turning off.



Fast Charge: This is captured during the constant-current phase. The two negative spikes are the result of the short delay when switching between the top and bottom FETs. The break-before-make action prevents current shoot-through and results in a body diode drop below ground potential during the *break* time.



Charge during Voltage Regulation and Approaching Termination: Note that this waveform is similar to the precharge waveform. The difference is that the battery voltage is higher so the duty cycle is slightly higher. The bottom FET stays on longer because there is more of a current load than during precharge; it takes longer for the inductor current to ramp down to the current threshold where the synchronous FET is disabled.



# bq24105-Q1

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### **REVISION HISTORY**

Changes	from	Original	(Δunust	2009) to	<b>Revision A</b>
Changes	nom	Unginal	(Auyusi,	2009) 10	REVISION A

Page
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Updated V <sub>OREG</sub> formula to match the BQ24105 commercial datasheet.	13	5
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27-Jul-2013

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)		(3)		(4/5)	
BQ24105IRHLRQ1	ACTIVE	VQFN	RHL	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	BQ24105	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs. LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available. OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above. Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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#### OTHER QUALIFIED VERSIONS OF B024105-01 ·

Addendum-Page 1



Catalog: BQ24105

27-Jul-2013

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

Addendum-Page 2



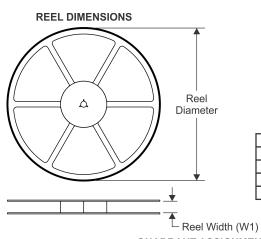
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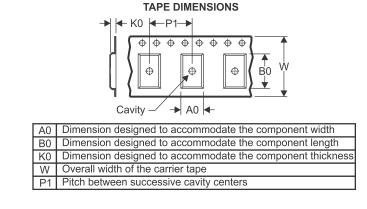
TEXAS INSTRUMENTS

# PACKAGE MATERIALS INFORMATION

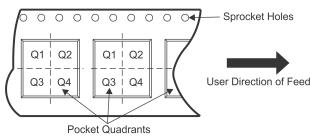
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## TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ24105IRHLRQ1	VQFN	RHL	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1

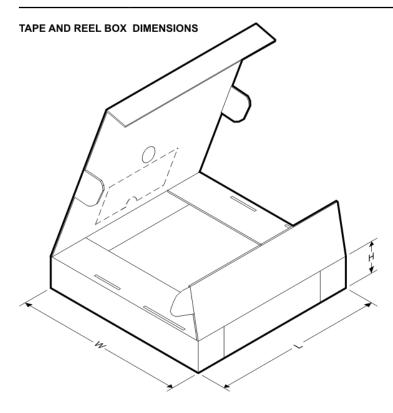


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## PACKAGE MATERIALS INFORMATION

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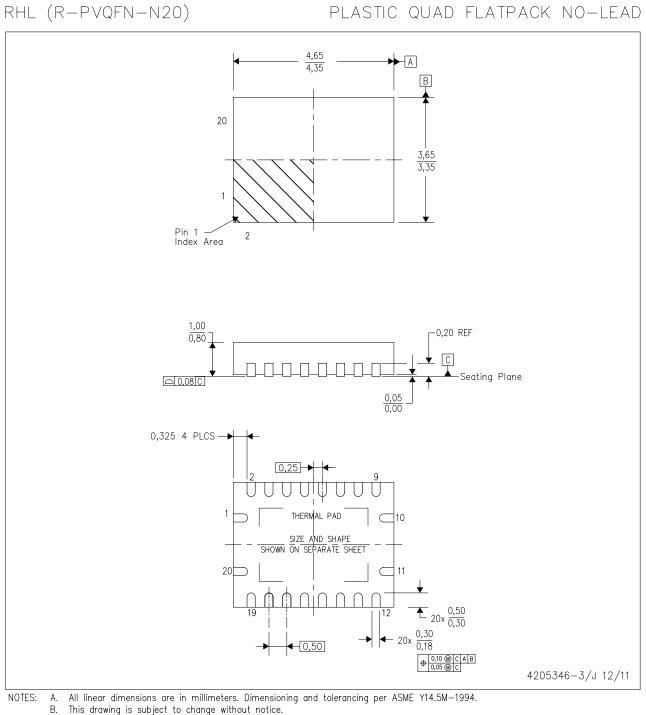


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BQ24105IRHLRQ1	VQFN	RHL	20	3000	367.0	367.0	35.0



## **MECHANICAL DATA**

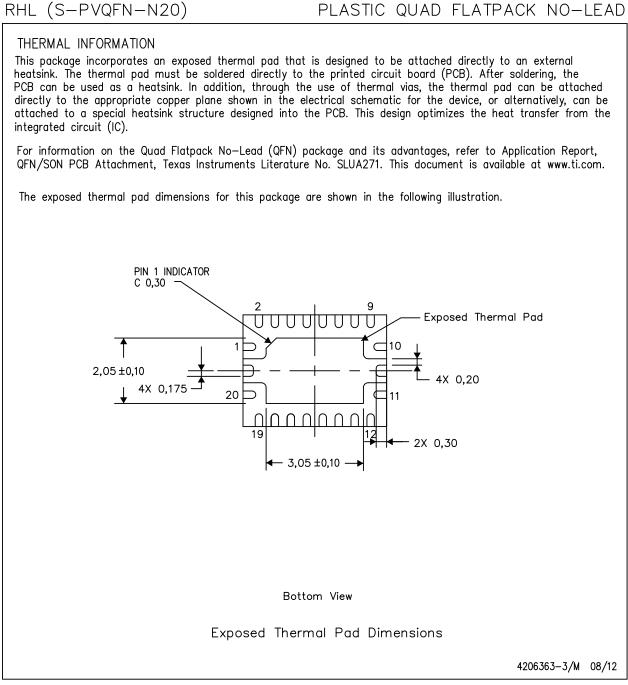


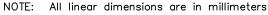
- This drawing is subject to change without notice. C.
- QFN (Quad Flatpack No-Lead) Package configuration. D.
- The package thermal pad must be soldered to the board for thermal and mechanical performance. Ε.
  - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.





## THERMAL PAD MECHANICAL DATA

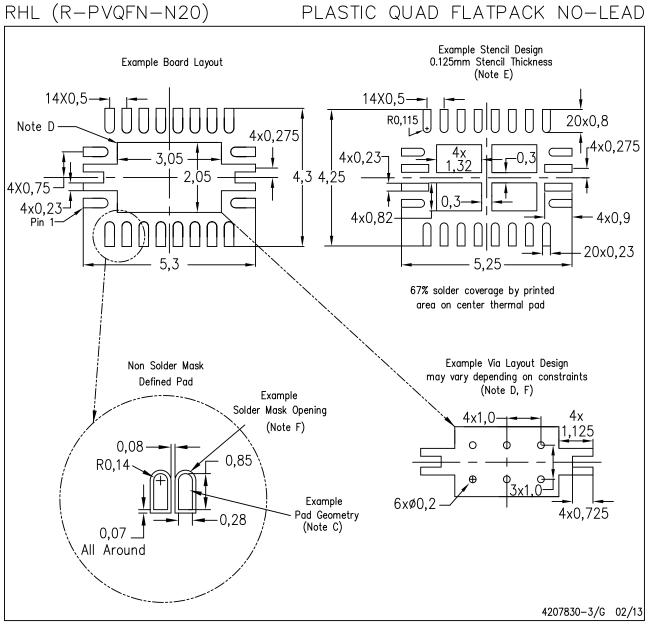








## LAND PATTERN DATA



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="http://www.ti.com">www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.





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